

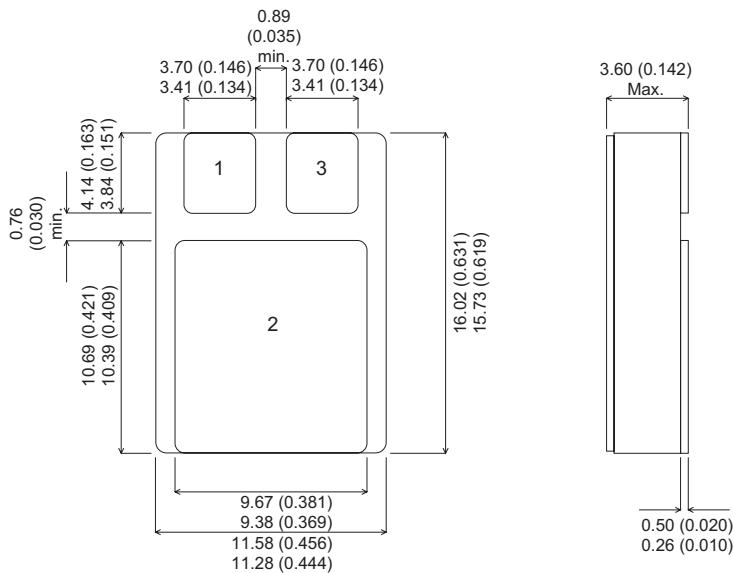


**SEMELAB**

**IRFN5210**

## MECHANICAL DATA

Dimensions in mm (inches)



**SMD 1 PACKAGE (TO-276AB)**

Pad 1 – Source

Pad 2 – Drain

Pad 3 – Gate

## P-CHANNEL POWER MOSFET

<b>V<sub>DSS</sub></b>	<b>-100V</b>
<b>I<sub>D(cont)</sub></b>	<b>-31A</b>
<b>R<sub>DS(on)</sub></b>	<b>0.060Ω</b>

## FEATURES

- HERMETICALLY SEALED SURFACE MOUNT PACKAGE
- SMALL FOOTPRINT – EFFICIENT USE OF PCB SPACE.
- SIMPLE DRIVE REQUIREMENTS
- LIGHTWEIGHT
- HIGH PACKING DENSITIES

**Note:** IRF5210SMD also available with pins 1 and 3 reversed.

## ABSOLUTE MAXIMUM RATINGS ( $T_{case} = 25^\circ\text{C}$ unless otherwise stated)

$V_{GS}$	Gate – Source Voltage	$\pm 20\text{V}$
$I_D$	Continuous Drain Current ( $V_{GS} = 0, T_{case} = 25^\circ\text{C}$ )	-31A
$I_D$	Continuous Drain Current ( $V_{GS} = 0, T_{case} = 100^\circ\text{C}$ )	-19A
$I_{DM}$	Pulsed Drain Current <sup>1</sup>	-124A
$P_D$	Power Dissipation @ $T_{case} = 25^\circ\text{C}$	125W
	Linear Derating Factor	1.0W/ $^\circ\text{C}$
$E_{AS}$	Single Pulse Avalanche Energy <sup>2</sup>	340mJ
$dv/dt$	Peak Diode Recovery <sup>3</sup>	4.0V/ns
$T_J, T_{stg}$	Operating and Storage Temperature Range	-55 to 150 $^\circ\text{C}$
$T_L$	Package Mounting Surface Temperature (for 5 sec)	300 $^\circ\text{C}$
$R_{\theta JC}$	Thermal Resistance Junction to Case	1.0 $^\circ\text{C}/\text{W}$

**Notes** 1) Pulse Test: Pulse Width  $\leq 300\text{ms}$ ,  $\delta \leq 2\%$

2) @  $V_{DD} = -25\text{V}$ ,  $L = 1.9\text{mH}$ , Peak  $I_{AS} = -19\text{A}$ ,  $V_{GS} = -10\text{V}$ ,  $R_G = 25\Omega$ , Starting  $T_J = 25^\circ\text{C}$

3) @  $I_{SD} \leq -19\text{A}$ ,  $di/dt \leq -390\text{A}/\mu\text{s}$ ,  $V_{DD} \leq -100\text{V}$ ,  $T_J \leq 150^\circ\text{C}$

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

**Semelab plc.** Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

E-mail: [sales@semelab.co.uk](mailto:sales@semelab.co.uk) Website: <http://www.semelab.co.uk>

Document Number 5587

Issue 1



**SEMELAB**

**IRFN5210**

## ELECTRICAL CHARACTERISTICS ( $T_{amb} = 25^\circ C$ unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
<b>STATIC ELECTRICAL RATINGS</b>					
$BV_{DSS}$	Drain – Source Breakdown Voltage $V_{GS} = 0$ $I_D = -250\mu A$	-100			V
$\Delta BV_{DSS}$	Temperature Coefficient of Breakdown Voltage Reference to $25^\circ C$ $I_D = -1mA$		-0.11		$V/^\circ C$
$R_{DS(on)}$	Static Drain – Source On-State Resistance 1 $V_{GS} = -10V$ $I_D = -19A$			0.06	$\Omega$
$V_{GS(th)}$	Gate Threshold Voltage $V_{DS} = V_{GS}$ $I_D = -250\mu A$	-2.0		-4.0	V
$g_{fs}$	Forward Transconductance 1 $V_{DS} = -50V$ $I_{DS} = -19A$	10			$S(V)$
$I_{DSS}$	Zero Gate Voltage Drain Current $V_{GS} = 0$ $V_{DS} = -80V$ $T_J = 125^\circ C$			-25 -250	$\mu A$
$I_{GSS}$	Forward Gate – Source Leakage $V_{GS} = -20V$			-100	nA
$I_{GSS}$	Reverse Gate – Source Leakage $V_{GS} = 20V$			100	
<b>DYNAMIC CHARACTERISTICS</b>					
$C_{iss}$	Input Capacitance $V_{GS} = 0$		2700		pF
$C_{oss}$	Output Capacitance $V_{DS} = -25V$		830		
$C_{rss}$	Reverse Transfer Capacitance $f = 1MHz$		470		
$Q_g$	Total Gate Charge 1 $V_{GS} = -10V$ $I_D = -19A$ $V_{DS} = -80V$			215	nC
$Q_{gs}$	Gate – Source Charge 1 $V_{GS} = -10V$ $I_D = -19A$			30	nC
$Q_{gd}$	Gate – Drain (“Miller”) Charge 1 $V_{DS} = -80V$			115	
$t_{d(on)}$	Turn-On Delay Time			28	ns
$t_r$	Rise Time			150	
$t_{d(off)}$	Turn-Off Delay Time			103	
$t_f$	Fall Time			116	
<b>SOURCE – DRAIN DIODE CHARACTERISTICS</b>					
$I_S$	Continuous Source Current			-31	A
$I_{SM}$	Pulse Source Current 2			-124	
$V_{SD}$	Diode Forward Voltage $I_S = -19A$ $T_J = 25^\circ C$ $V_{GS} = 0$			-1.6	V
$t_{rr}$	Reverse Recovery Time $I_F = -19A$ $T_J = 25^\circ C$			290	ns
$Q_{rr}$	Reverse Recovery Charge $d_i / d_t \leq 100A/\mu s$ $V_{DD} \leq -50V$			2.1	$\mu C$
$t_{on}$	Forward Turn-On Time		Negligible		

### Notes

- 1) Pulse Test: Pulse Width  $\leq 300ms$ ,  $\delta \leq 2\%$
- 2) Repetitive Rating – Pulse width limited by maximum junction temperature.

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

**Semelab plc.** Telephone +44(0)1455 556565. Fax +44(0)1455 552612.

E-mail: [sales@semelab.co.uk](mailto:sales@semelab.co.uk) Website: <http://www.semelab.co.uk>

Document Number 5587

Issue 1